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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/603,689	06/26/2003	Hidetoshi Ohnuma	SON-2769	2872
23353 75	590 02/13/2006		EXAM	INER
RADER FISHMAN & GRAUER PLLC LION BUILDING			CHACKO DAV	IS, DABORAH
1233 20TH STREET N.W., SUITE 501			ART UNIT	PAPER NUMBER
WASHINGTO	N, DC 20036		1756	

DATE MAILED: 02/13/2006

Please find below and/or attached an Office communication concerning this application or proceeding.

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	Application No.	Applicant(s)
	10/603,689	OHNUMA, HIDETOSHI
Office Action Summary	Examiner	Art Unit
	Daborah Chacko-Davis	1756
The MAILING DATE of this communication ap Period for Reply	pears on the cover sheet with	the correspondence address
A SHORTENED STATUTORY PERIOD FOR REPL WHICHEVER IS LONGER, FROM THE MAILING D.  - Extensions of time may be available under the provisions of 37 CFR 1. after SIX (6) MONTHS from the mailing date of this communication.  - If NO period for reply is specified above, the maximum statutory period Failure to reply within the set or extended period for reply will, by statut Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).	DATE OF THIS COMMUNICA 136(a). In no event, however, may a reply will apply and will expire SIX (6) MONTH: te, cause the application to become ABAN	TION.  be timely filed  from the mailing date of this communication.  DONED (35 U.S.C. § 133).
Status		
3) Since this application is in condition for allowa	s action is non-final. ance except for formal matters	·
closed in accordance with the practice under	Ex parte Quayle, 1935 C.D. 1	1, 453 O.G. 213.
Disposition of Claims		
4)  Claim(s) 1-7 and 15-20 is/are pending in the a 4a) Of the above claim(s) is/are withdra 5)  Claim(s) is/are allowed. 6)  Claim(s) 1-7 and 15-20 is/are rejected. 7)  Claim(s) is/are objected to. 8)  Claim(s) are subject to restriction and/o	awn from consideration.	
Application Papers		
9) The specification is objected to by the Examina 10) The drawing(s) filed on is/are: a) accomposed and applicant may not request that any objection to the Replacement drawing sheet(s) including the correct to be a control of the control	cepted or b) objected to by drawing(s) be held in abeyance ction is required if the drawing(s)	. See 37 CFR 1.85(a). is objected to. See 37 CFR 1.121(d).
Priority under 35 U.S.C. § 119		
12) Acknowledgment is made of a claim for foreign a) All b) Some * c) None of:  1. Certified copies of the priority document 2. Certified copies of the priority document 3. Copies of the certified copies of the priority application from the International Bureat*  * See the attached detailed Office action for a list.	nts have been received. Its have been received in Apportity documents have been reau (PCT Rule 17.2(a)).	lication No ceived in this National Stage
Attachment(s)  1) Notice of References Cited (PTO-892)  2) Notice of Draftsperson's Patent Drawing Review (PTO-948)  3) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08 Paper No(s)/Mail Date		nmary (PTO-413) Iail Date mal Patent Application (PTO-152)

### **DETAILED ACTION**

#### Election/Restrictions

1. Applicant's election of Group I, claims 1-7, and 15-20, in the reply filed on August 3, 2005, is acknowledged. Because applicant did not distinctly and specifically point out the supposed errors in the restriction requirement, the election has been treated as an election without traverse (MPEP § 818.03(a)). The non-elected invention, Group II, claims 8-14, was cancelled in the reply filed on August 3, 2005.

# Claim Rejections - 35 USC § 102

2. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

- (e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.
- 3. Claims 1-7, 15-20, are rejected under 35 U.S.C. 102(e) as being anticipated by U.S. Patent Application Publication No. 2003/0138742 (Irie et al., herein after referred to as Irie).

Irie, in the abstract, in [0013], [0015], [0022], [0041], [0095], [0132], [0134], [0135], [0136], [0137], [0145], [0146], [0162], [0163], [0175], [0201], [0202], [0203], [0204], and in figures 2B, 4, and 6, discloses a method of projecting a desired pattern (photolithography) on a device substrate (object to be exposed) using a reflective mask

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(reticle for use in the EUV exposure region) comprising providing reticles (master reticles R1....RN) each having pattern elements (mark elements) with mark elements aligned in the X-direction (125X, mark elements horizontal to the projection vector), and mark elements aligned in the Y-direction (125Y, mark elements perpendicular to the projection vector), wherein the reticle is rotated by rotational means (main control system) so as to align the corresponding mark elements (either mark element in the Xdirection or mark element in the Y-direction) in the Z-direction (projection vector, best focus position), and performing sequential exposures (X-direction elements rotated about 90 degree to align in the projection beam, and Y-direction elements rotated about 90 degree to align with the projection beam, performing plural exposures) through the respective reticles, while adjusting the tilt angles by rotating the substrate and the reticles (125X, and 125Y) through the main control system thereby canceling any errors (due to angle deviations) and forming the desired pattern on the substrate (reference 4) (claims 1-2, 6-7, 15-16, and 20). Irie, in [0200], [0204], discloses that the exposure light is either a EUV ray or an X-ray (claims 3, and 17). Irie, in [0133], discloses that the patterns can be formed on the substrate using an electron beam system (electron beam exposure performed) (claims 3, and 18). Irie, in [0029], [0109], [0119], and [0134], and in figures 2B, and 4, discloses that the reticle pattern that includes the mark elements formed in the Y-direction (125Y, V-line mask) relative to the projection vector (best focus position) corresponds to the scanning direction (operating direction) of the optical system (exposure system) (claims 5, and 19).

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## Conclusion

4. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Daborah Chacko-Davis whose telephone number is (571) 272-1380. The examiner can normally be reached on M-F 9:30 - 6:00. If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Mark F Huff can be reached on (571) 272-1385. The fax phone number for the organization where this application or proceeding is assigned is (571) 273-8300. Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

dcd

February 7, 2006.

JOHN Å. MCPHERSON PRIMARY EXAMINER

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